

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Ricky Amos

Group Art Unit: 2815

Serial No.: 09/995,031

Examiner: Matthew Landau

Filed: Nov. 29, 2001

In Response to Office Action
Dated: Jan. 22, 2003

For: High Temperature Processing Compatible Metal Gate
Electrode For FETs and Method for Fabrication

Attorney Docket No.: YOR920010633US1 (062)

of Amendments
3/27/03

A. N. E. I
ENTER/RCC

Certificate of Facsimile

I hereby certify that this paper (along with any referred to as being attached or enclosed) is being deposited with the United States Patent Office via facsimile on (703) 872-9319 on March 24, 2003

[Signature]
Kathy Dixon

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REQUEST FOR RECONSIDERATION

Assistant Commissioner
for Patents
Washington, D.C. 20231

Dear Sir:

In response to a final Office Action mailed January 22, 2003, please enter the following amendments and consider the following remarks.